NSN 5961-01-063-9942

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-063-9942

Inclosure Material:

Glass

Overall Length:

0.210 inches

Overall Diameter:

0.230 inches

Electrode Internally-electrically Connected To Case:

Collector

Mounting Method:

Terminal

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

40.0 collector to emitter voltage/static/base open

Current Rating Per Characteristic:

150.00 milliamperes source cutoff current

Power Rating Per Characteristic:

400.0 milliwatts small-signal input power, common-collector absolute

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius ambient air

Special Features:

Junction pattern arrangement: pnp

Test Data Document:

98230-0n225122 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing,

etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

3 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

A110a0